

Description

The SXESDMC2XD5VB protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage.

Feature

40W peak pulse power per line ($t_P = 8/20\mu s$)
 DFN0603-2L package
 Replacement for MLV(0201)
 Bidirectional configurations
 Response time is typically $< 1ns$
 Low clamping voltage
 RoHS compliant
 Transient protection for data lines to
 IEC61000-4-2(ESD) $\pm 15KV$ (air), $\pm 15KV$ (contact);
 IEC61000-4-4 (EFT) 40A (5/50ns)

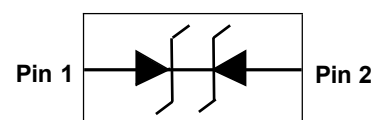
Applications

Cellular phones
 Portable devices
 Digital cameras
 Power supplies

Mechanical Characteristics

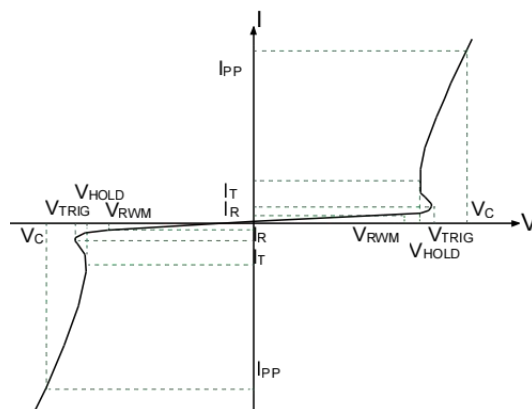
Mounting position: Any
 Qualified max reflow temperature: $260^{\circ}C$
 Device meets MSL 1 requirements
 DFN0603-2L without plating

DFN0603-2L



Electronics Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{TRIG}	Reverse trigger Current
V_{HOLD}	Reverse holding voltage
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance
I_F	Forward Current
V_F	Forward Voltage @ I_F



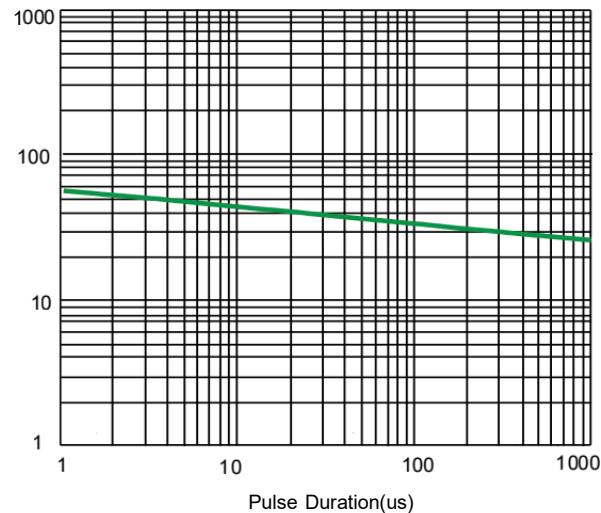
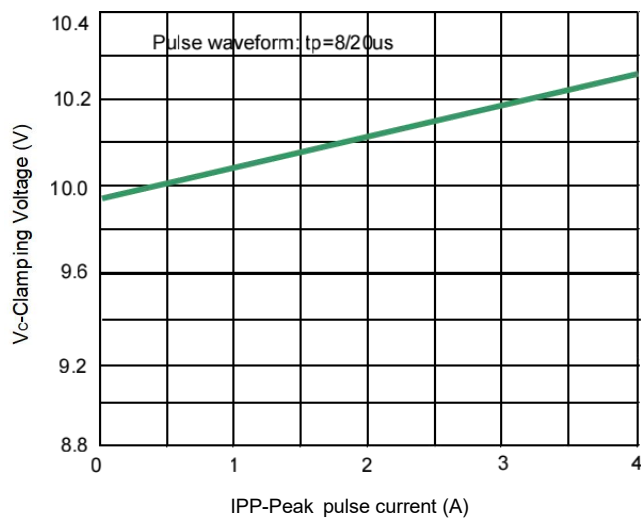
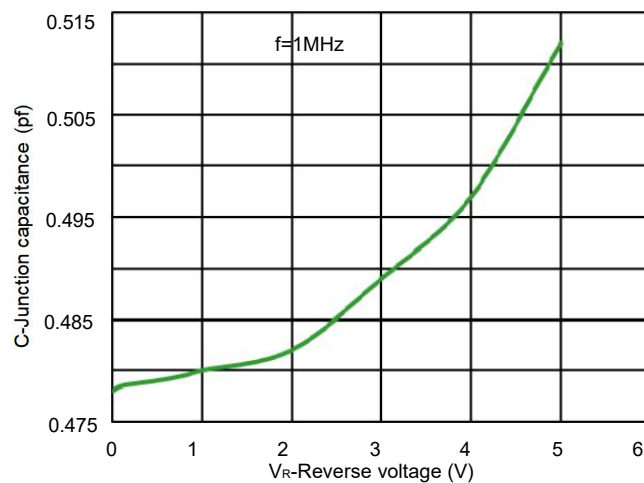
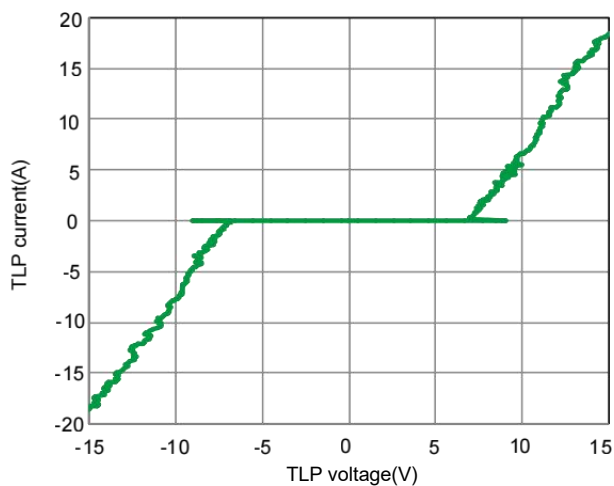
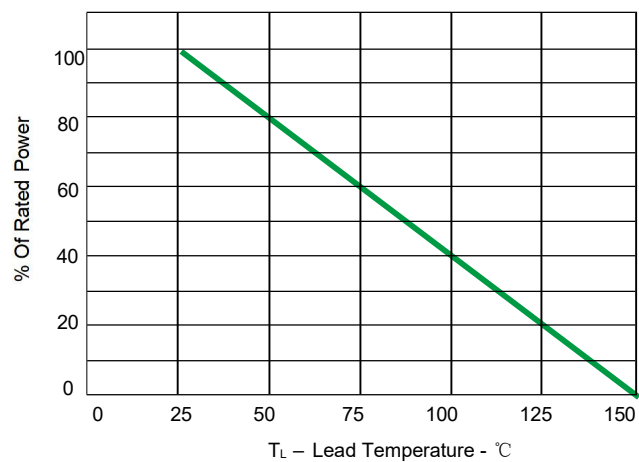
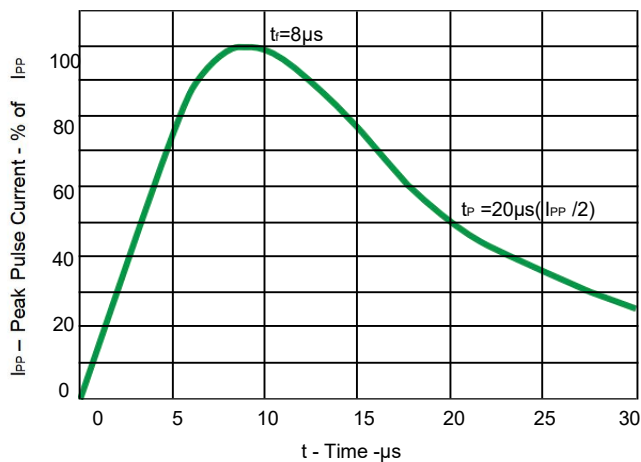
Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				5.0	V
Reverse trigger voltage	V_{TRIG}	$I_{TRIG}=30mA$	8.0	9.2	10.5	V
Reverse holding voltage	V_{HOLD}	$I_{HOLD}=60mA$	6.0	7.0	8.0	V
Reverse Leakage Current	I_R	$V_{RWM} = 5V$ $T=25^{\circ}C$			1.0	μA
Maximum Reverse Peak Pulse Current	I_{PP}			4.2		A
Clamping Voltage	V_{CL}	$I_{PP}=16A$ $t_p=100ns$		14.0		V
Clamping Voltage	V_C	$I_{PP}=1A$		10	12	V
Clamping Voltage	V_C	$I_{PP}=3A$		10	12	V
Clamping Voltage	V_C	$I_{PP}=4A$		10	12	V
Junction Capacitance	C_J	$V_R=0V$ $f = 1MHz$		0.42	0.5	pF

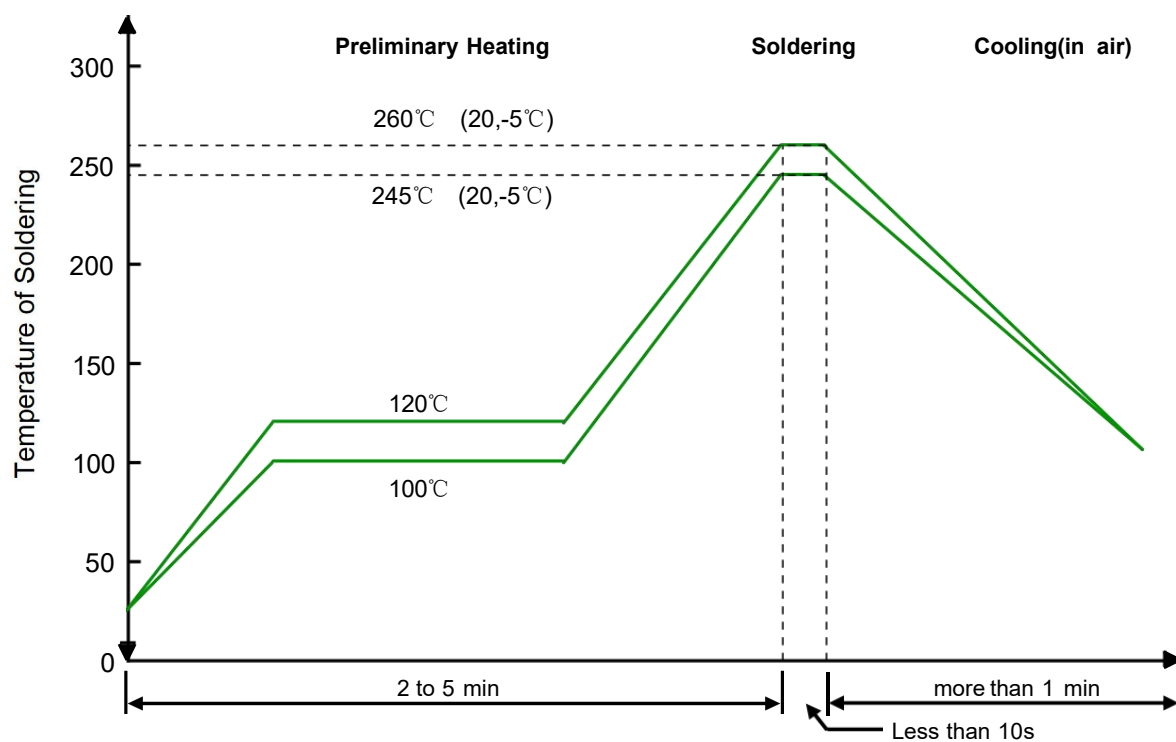
Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p=8/20\mu s$)	P_{pp}	40	W
Operating Temperature	T_J	-55 to 150	$^{\circ}C$
Storage Temperature	T_{STG}	-55 to 150	$^{\circ}C$

Typical Characteristics

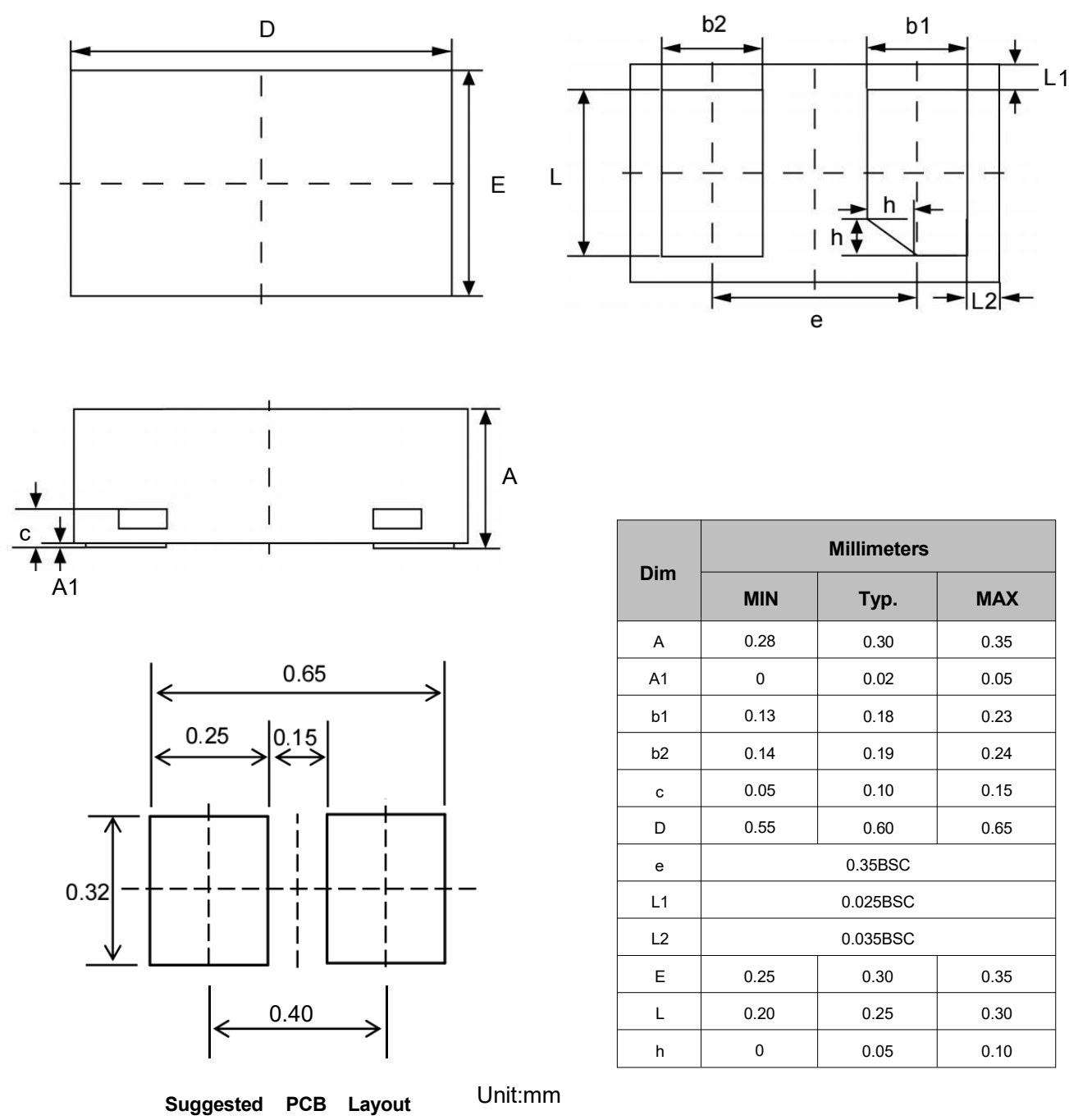


Solder Reflow Recommendation



Remark: Pb free for 260°C ; Pb for 245°C .

Product dimension (DFN0603-2L)



Ordering information

Device	Package	Reel	Shipping
TAPING	DFN0603-2L (Pb-Free)	7"	12000 / Tape & Reel